



A Product Line of Diodes Incorporated



# FCX789A

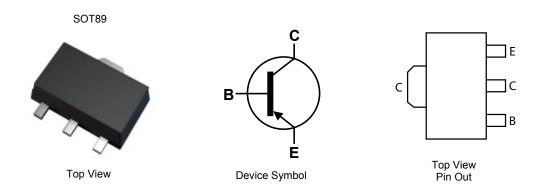
#### 25V PNP MEDIUM POWER TRANSISTOR IN SOT89

#### Features

- BV<sub>CEO</sub> > -25V
- $I_C = -3A$  high Continuous Current
- I<sub>CM</sub> = -8A Peak Pulse Current
- Low saturation voltage V<sub>CE(sat)</sub> < -320mV @ -3A</li>
- h<sub>FE</sub> specified up to -8A for high current gain hold up
- Complementary NPN Type: FCX688B
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT89
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>(23)</sup>
- Weight: 0.05 grams (Approximate)



### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX789ATA	789	7	12	1,000
		•		

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and</li>

<1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

### **Marking Information**

Notes:







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### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-25	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-25	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-3	A
Peak Pulse Current	I <sub>CM</sub>	-8	A

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissinction	(Note 5)		1	W	
Power Dissipation	(Note 6) P <sub>D</sub>		2	vv	
Thermal Desistance Junction to Ambient Air	(Note 5)	D	125	0000	
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ hetaJA}$	62.5	°C/W	
Thermal Resistance, Junction to Leads (Note 7)		R <sub>θJL</sub>	5.31	°C/W	
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

#### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes: 5. For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.

6. Same as note (5), except the device is mounted on 40mm X 40mm FR4 PCB.

7. Thermal resistance from junction to solder-point (at the end of collector lead).

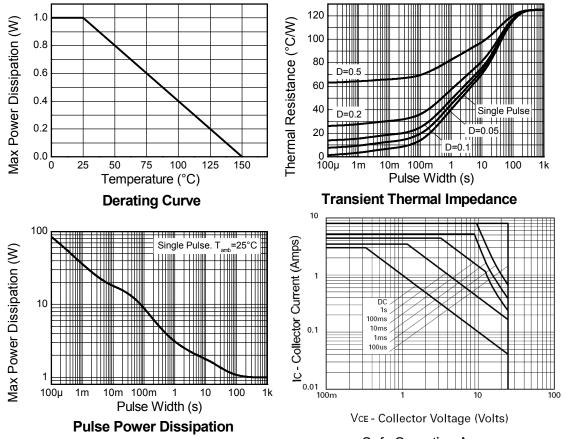
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.







## Thermal Characteristics and Derating Information



Safe Operating Area





**FCX789A** 

Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-25	-	-	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-25	-	-	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.1	-	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CBO</sub>	-	<1	-100	nA	V <sub>CB</sub> = -15V
Emitter Cutoff Current	I <sub>EBO</sub>	-	<1	-100	nA	V <sub>EB</sub> = -5.6V
DC current transfer Static ratio (Note 9)	h <sub>FE</sub>	300 230 180 75	500 320 250 120	800 - - -	-	$\begin{split} I_{C} &= -10 \text{mA}, \ V_{CE} = -2 V \\ I_{C} &= -1 \text{A}, \ V_{CE} = -2 V \\ I_{C} &= -2 \text{A}, \ V_{CE} = -2 V \\ I_{C} &= -6 \text{A}, \ V_{CE} = -2 V \end{split}$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>		-130 -290 -250	-190 -400 -320	mV	$I_{C} = -1A$ , $I_{B} = -10mA$ $I_{C} = -2A$ , $I_{B} = -20mA$ $I_{C} = -3A$ , $I_{B} = -100mA$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	-	-0.8	-0.9	V	I <sub>C</sub> = -1A, I <sub>B</sub> = -10mA
Base-Emitter Turn-on Voltage (Note 9)	V <sub>BE(on)</sub>	-	-0.8	-	V	I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V
Transitional Frequency	f <sub>T</sub>	100	-	-	MHz	I <sub>C</sub> = -50mA, V <sub>CE</sub> = -5V f = 50MHz
Input capacitance	C <sub>ibo</sub>	-	225	-	pF	V <sub>EB</sub> = -0.5V, f = 1MHz,
Output capacitance	C <sub>obo</sub>	-	25	-	pF	V <sub>CB</sub> = -10V, f = 1MHz,
Switching times	t <sub>on</sub>		35		nS	I <sub>C</sub> = -500mA, V <sub>CC</sub> = -10V
	t <sub>off</sub> -		400	-	115	$I_{B1} = -I_{B2} = -50 \text{mA}$

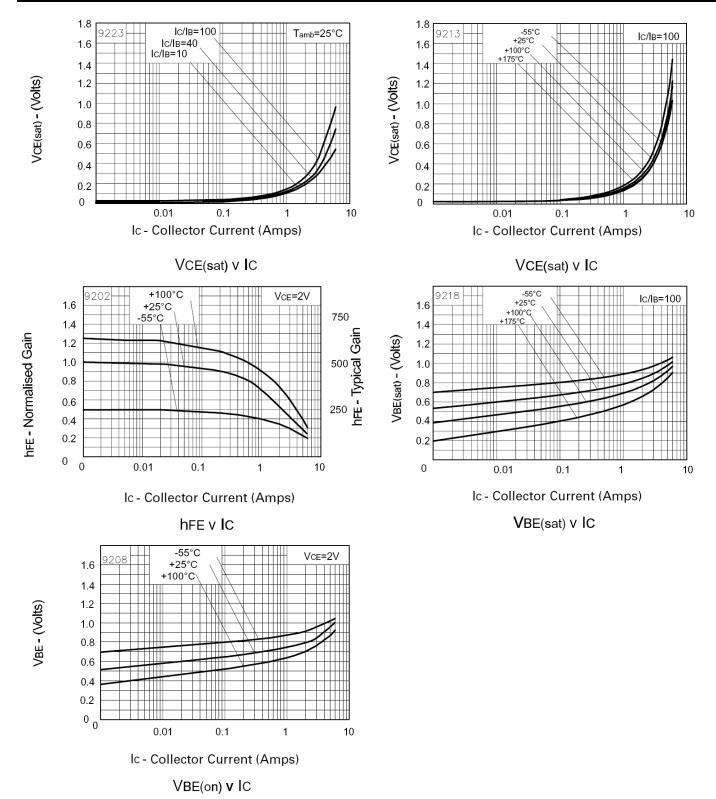
9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%. Notes:







## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



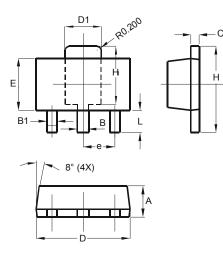






### **Package Outline Dimensions**

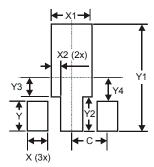
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
ш	2.29	2.60		
е	1.50 Typ			
Н	3.94 4.25			
H1	2.63 2.93			
L	0.89 1.20			
All [	All Dimensions in mm			

### Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500





## **FCX789A**

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